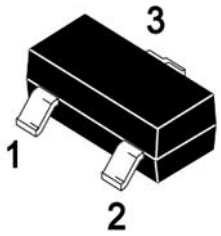
SSCP2907AGS7

PNP Switching Transistor

➢ Features

VCB	VCE	VEB	IC
-60V	-60V	-5V	-600mA

➢ Pin configuration



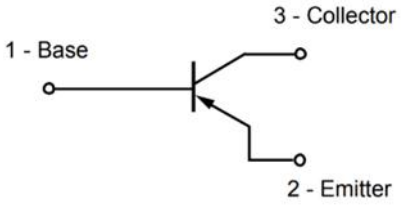
SOT-323

➢ Description

This product is general usage and suitable for many different applications. It can be used for medium power amplifiers and switches requiring collector currents up to 500 mA.

➢ Applications

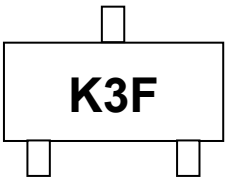
- Low current and high precision circuits such preamplifiers, oscillators, current mirror configuration
- Medium power amplification and switching



Circuit Diagram

➢ Ordering Information

Device	Package	Shipping
SSCP2907AGS7	SOT-323	3000/Reel



Marking(Top View)

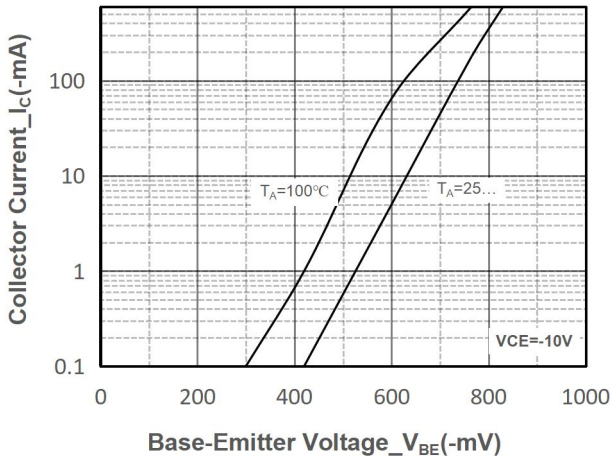
➢ Absolute Maximum Ratings(T_A=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-60	V
Collector- Emitter Voltage	V_{CEO}	-60	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current-Continuous	I_C	-600	mA
Collector Power Dissipation	P_C	225	mW
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-55 to 150	℃

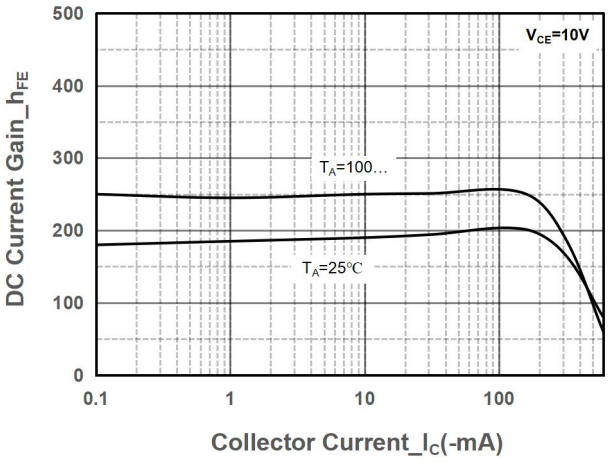
➢ Electrical Characteristics (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	BV_{CBO}	I_C=-100uA,I_E=0	-60			V
Collector-emitter Breakdown Voltage	BV_{CEO}	I_C=-1mA,I_B=0	-60			V
Emitter -Base Breakdown Voltage	BV_{EBO}	I_E=-100uA,I_C=0	-5			V
Collector Cutoff Current	I_{CBX}	V_{CE}=-30V, V_{EB}=-0.5V,			-50	nA
Collector Cutoff Current	I_{CBO}	V_{CB}=-50V,I_E=0			-20	nA
Emitter Cutoff Current	I_{EBO}	V_{EB}=-3V,I_C=0			-10	nA
DC Current Gain	h_{FE1}	V_{CE}=-10V,I_C=-150mA	100		300	
	h_{FE2}	V_{CE}=-10V,I_C=-0.1mA	75			
	h_{FE3}	V_{CE}=-10V,I_C=-500mA	50			
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=-500mA,I_B=-50mA			-1.6	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	I_C=-500mA,I_B=-50mA			-2.6	V
Transition frequency	f_T	V_{CE}=-20V,I_C=-50mA f=100MHz	250			MHz
Delay Time	t_d	V_{CC}=-30V,I_C=-150mA, I_{B1}=-15mA			10	ns
Rise Time	t_r	V_{CC}=-30V,I_C=-150mA, I_{B1}=-15mA			25	ns
Storage Time	t_s	V_{CC}=-6V,I_C=-150mA, I_{B1}= -I_{B2}=-15mA			225	ns
Fall Time	t_f	V_{CC}=-6V,I_C=-150mA, I_{B1}=-I_{B2}=-15mA			60	ns

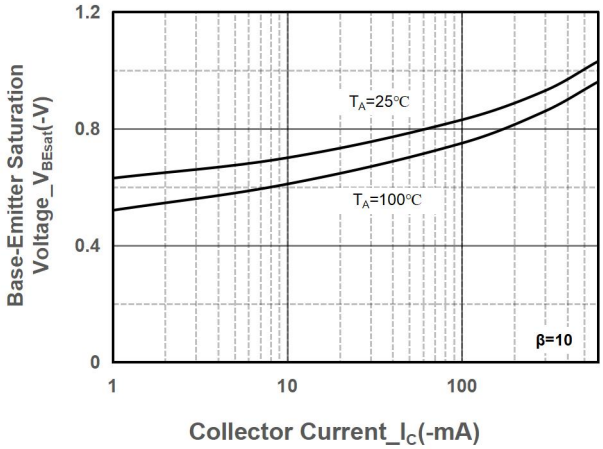
➢ Typical Performance Characteristics (T_A=25℃ unless otherwise noted)



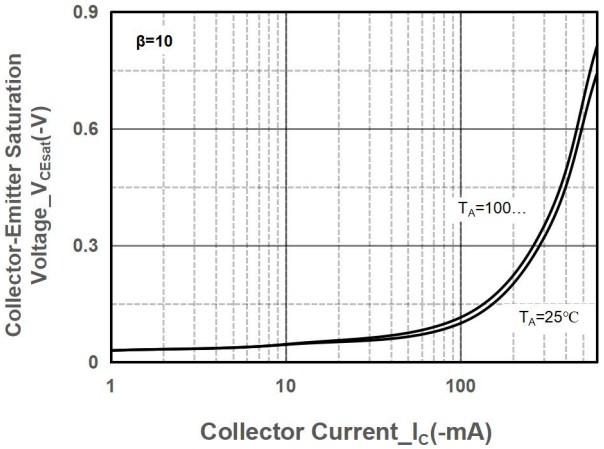
Collector Current vs. Base-Emitter Voltage



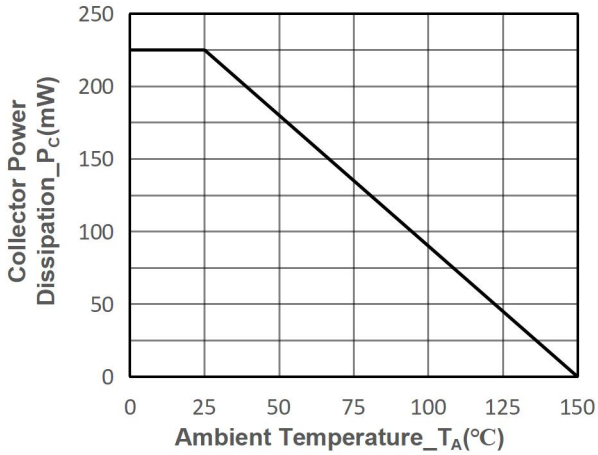
DC Current Gain vs. Collector Current



$V_{BE(sat)}$ vs. Collector Current

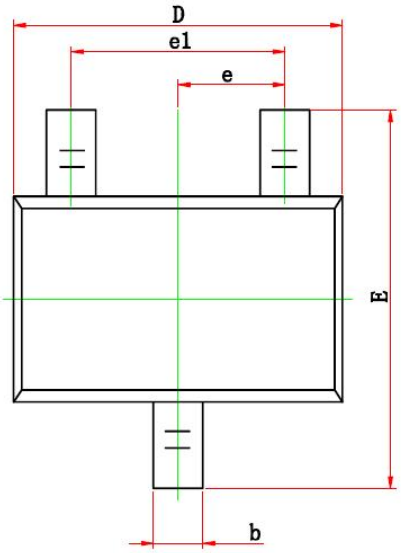


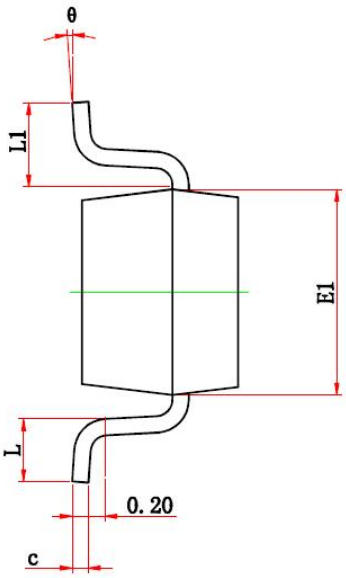
$V_{CE(sat)}$ vs. Collector Current

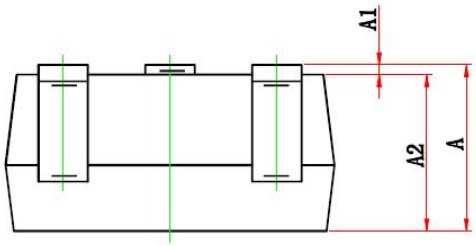


Power derating vs. Ambient temperature

- **Package Information**







Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	2.150	2.450	0.085	0.096
E1	1.150	1.350	0.045	0.053
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.260	0.460	0.010	0.018
L1	0.525 REF.		0.021 REF.	
θ	0°	8°	0°	8°

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